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PAWR I - Power Amplifier Modeling & Design

<i>Power Amplifiers in Cable Access Network</i>	
Zhixiong Ren (Huawei, P.R. China), Xiaoshu Si (Huawei, P.R. China), Tao Ouyang (Huawei, P.R. China)	1
<i>Cardiff Behavioural Model Analysis using a Two-Tone Stimulus</i>	
Azam Al-Rawachy (Cardiff University, United Kingdom (Great Britain) & Mosul University, Iraq), Thoalfukar Hussein (Technical Institute of Karbala, Al-Furat Al-Awsat Technical University, United Kingdom (Great Britain)), Johannes Benedikt (Cardiff University, United Kingdom (Great Britain)), Paul J Tasker (Cardiff University, United Kingdom (Great Britain)), James Joseph Watson Bell (Cardiff University, United Kingdom (Great Britain))	5
<i>Evidence for the Self-Enhanced Class J PA Operating Mode From Harmonic Load-Pull Measurements</i>	
Frederik Vanaverbeke (NXP Semiconductors, USA), Kevin Kim (RF Power, NXP Semiconductors, Chandler, AZ, USA), Philip Saint-erne (NXP Semiconductors, USA)	9
<i>Automatic Algorithm for the Direct Design of Asymmetric Doherty Power Amplifiers</i>	
Chenyu Liana (The Ohio State University, USA), Patrick Roblin (The Ohio State University, USA), Yunsik Hahn (The Ohio State University, USA)	13
<i>Simplified analysis of the effect of load variation in common Doherty power amplifier architectures</i>	
Roberto Quaqlia (Cardiff University, United Kingdom (Great Britain)), Jonathan Lees (Cardiff University, United Kingdom (Great Britain))	17

PAWR II High-Efficiency RF Power Amplifiers

<i>A Ka-Band Asymmetric Dual Input CMOS SOI Doherty Power Amplifier with 25 dBm Output Power and High Back-Off Efficiency</i>	
Narek Rostomyan (University of California San Diego, USA), Mustafa Ozen (University of California San Diego, USA), Peter Asbeck (University of California, San Diego, USA)	41
<i>A 40-MHz Bandwidth Pulse-Modulated Polar Transmitter for Mobile Applications</i>	
You-Huei Chen (National Taiwan University, Taiwan), Tzu-Han Wang (National Taiwan University, Taiwan), Shu-Chen Lin (National Taiwan University, Taiwan), Jau-Horng Chen (National Taiwan University, Taiwan), Yi-Jan Emery Chen (National Taiwan University, Taiwan)	45
<i>Design of a 110 W Wideband Inverse Class-F GaN HEMT Power Amplifier with 65% Efficiency over 100-1000 MHz Bandwidth</i>	
Adnan Raza (Qorvo, USA), Jeff Gengler (Qorvo, USA)	48

PAWR III RF Power Amplifier Technology

<i>Ka-Band 3-Stack Power Amplifier with 18.8 dBm Psat and 23.4 % PAE Using 22nm CMOS FDSOI Technology</i>	
Janne P Aikio (University of Oulu, Finland), Timo Rahkonen (University of Oulu, Finland), Aarno Pärssinen (University of Oulu, Finland), Nuutti Tervo (University of Oulu, Finland), Mikko Hietanen (University of Oulu, Finland)	79
<i>Ka-Band GaN-on-Si 4W MMIC High Power Amplifier for Millimetre-wave Radar</i>	
Elisa Cipriani (University of Rome Tor Vergata, Italy), Paolo Colantonio (University of Roma Tor Vergata, Italy), Franco Giannini (University of Tor Vergata, Rome, Italy)	82
<i>A 2-GHz Sampled Line Impedance Sensor for Power Amplifier Applications with Varying Load Impedance</i>	
Devon Donahue (University of Colorado, USA), Taylor Barton (University of Colorado, Boulder, USA)	85
<i>A Concurrent 2.2/3.9-GHz Dual-Band GaN Power Amplifier</i>	
Philip Zurek (University of Colorado at Boulder, USA), Tommaso Cappello (University of Colorado at Boulder, USA), Zoya Popović (University of Colorado at Boulder, USA)	88
<i>A Linearity Enhanced Power Recycling Pulse-Modulated Polar Transmitter Using Aliasing-Free Digital Pulsewidth Modulation</i>	
Tzu-Han Wang (National Taiwan University, Taiwan), You-Huei Chen (National Taiwan University, Taiwan), Shu-Chen Lin (National Taiwan University, Taiwan), Jau-Horng Chen (National Taiwan University, Taiwan)	92

PAWR IV Distortion Modeling and Reduction Techniques in RF Power Amplifiers

<i>Fixed Point Considerations for Digital Predistortion of a RF Power Amplifier Using Recursive Least Square (RLS) Estimation</i> R. Neil Braithwaite (Consultant, Orange 92867 USA, USA)	125
<i>A Reduced-Complexity Doubly Orthogonal Matching Pursuit Algorithm for Power Amplifier Sparse Behavioral Modeling</i> Juan A. Becerra (Universidad de Sevilla, Spain & University of Delaware, USA), Maria J. Madero-Ayora (Universidad de Sevilla, Spain), Javier Reina-Tosina (Universidad de Sevilla, Spain), Carlos Crespo-Cadenas (Universidad de Sevilla, Spain), Javier Garcia-Frias (University of Delaware, USA), Gonzalo Arce (University of Delaware, USA)	128
<i>Dynamic Selection and Update of Digital Predistorter Coefficients for Power Amplifier Linearization</i> Quynh Anh Pham (Universitat Politècnica de Catalunya, Spain), David López-Bueno (Centre Tecnològic de Telecomunicacions de Catalunya (CTTC/CERCA), Spain), Gabriel Montoro (Universitat Politècnica de Catalunya, Spain), Pere Gilabert (Universitat Politècnica de Catalunya, Spain)	131
<i>Characterization of Power Amplifiers under Multi-Tone Excitation for Wide-Bandwidth Carrier Aggregation Applications</i> Kevin Chuang (NanoSemi, Inc., USA)	135
<i>A Versatile Wideband Linearizer/Driver Amplifier for Use with Multiple Millimeter-wave TWTAs</i> Allen Katz (The College of New Jersey, USA), Robert Gray (Linearizer Technology, Inc, USA), Roger Dorval (Linearizer Technology, Inc, USA)	139

RWW Poster I

<i>Wideband High Efficiency Power Amplifier Design Using Precise High Frequency Parasitics Modeling/Compensation for GaN-HEMTs</i> Ahmed Sayed (Military Technical College & MTC, Egypt), Hesham Ahmed (Military Technical College, Egypt)	224
<i>Broadband Parallel Doherty Power Amplifier in GaN for 5G Applications</i> Jennifer Kitchen (ASU, USA), Sumit Bhardwaj (Arizona State University, USA)	228
<i>An Efficient Linear Power Amplifier with 2nd Harmonic Injection</i> Sushia Rahimizadeh (University of Colorado Boulder, USA), Tommaso Cappello (University of Colorado at Boulder, USA), Zoya Popović (University of Colorado at Boulder, USA)	231
<i>Gate Leakage Current Effects on the Linearity of 28GHz CMOS SOI Power Amplifiers</i> Baqher Rabet (University of California San Diego, USA), Narek Rostomyan (University of California San Diego, USA), Peter Asbeck (University of California, San Diego, USA)	235
<i>A 19-43 GHz Linear Power Amplifier in 28nm Bulk CMOS for 5G Phased Array</i> Mohamed Moussa Esmael (Analog Devices, Egypt), Mohamed Abdalla (Cairo University, Egypt), Islam Eshrah (Cairo University, Egypt)	239